

<u> UF2001 - UF2007</u>

Features

- Diffused Junction
- Ultra-Fast Switching for High Efficiency
- Surge Overload Rating to 60A Peak
- Low Reverse Leakage Current
- Lead Free Finish, RoHS Compliant (Note 4)

DO-15 Dim Min Max 25.40 Α В 5.50 7.62 С 0.686 0.889 D 2.60 3.60

All Dimensions in mm

Mechanical Data

- Case: DO-15
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Tin. Solderable per MIL-STD-202, Method 208 @3:
- Polarity: Cathode Band
- Marking: Type Number
- Ordering Information: See Page 3
- Weight: 0.4 grams (approximate)

Maximum Ratings and Electrical Characteristics

@T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic		Symbol	UF 2001	UF 2002	UF 2003	UF 2004	UF 2005	UF 2006	UF 2007	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage (Note 5)		V _{RRM} V _{RWM} V _R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage		V _{R(RMS)}	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1)	@ T _A = 50°C	Io		·	l	2.0	l	l		Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on R	ated Load	I _{FSM}				60				Α
Forward Voltage	@ I _F = 2.0A	V_{FM}		1.0		1.3		1.7		V
Peak Reverse Current at Rated DC Blocking Voltage (Note 5)	@ T _A = 25°C @ T _A = 100°C	I _{RM}	5.0 100			μА				
Reverse Recovery Time (Note 3)		t _{rr}		5	0			75		ns
Typical Total Capacitance (Note 2)		Ст		5	0			30		pF
Typical Thermal Resistance Junction to Ambient		$R_{\theta JA}$				50				°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}			-(65 to +15	50			°C

Notes:

- 1. Valid provided that leads are maintained at ambient temperature at a distance of 9.5mm from the case.
- Measured at 1.0MHz and applied reverse voltage of 4.0V DC. Measured at $I_F = 0.5A$, $I_R = 1.0A$, $I_{rr} = 0.25A$. See figure 5.
- RoHS revision 13.2.2003. High temperature solder exemption applied, see *EU Directive Annex Note* 7.
- 5. Short duration pulse test used to minimize self heating effect.

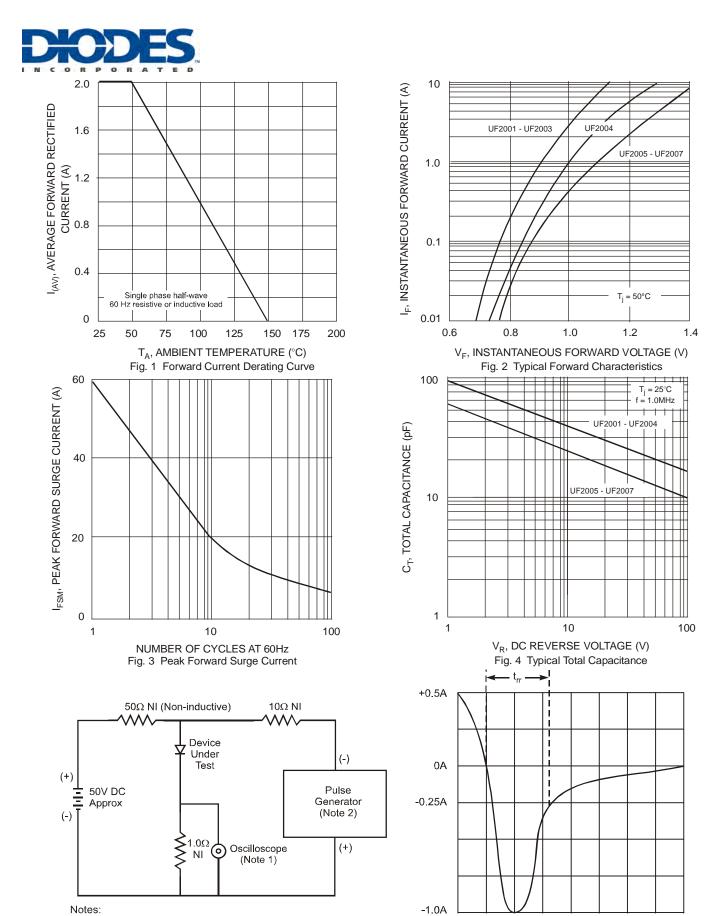


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

Set time base for 50/100 ns/cm

1. Rise Time = 7.0ns max. Input Impedance = $1.0M\Omega$, 22pF.

2. Rise Time = 10ns max. Input Impedance = 50Ω .



Ordering Information (Note 6)

Device	Packaging	Shipping		
UF2001-T	DO-15	4K/Tape & Reel, 13-inch		
UF2002-T	DO-15	4K/Tape & Reel, 13-inch		
UF2003-T	DO-15	4K/Tape & Reel, 13-inch		
UF2004-T	DO-15	4K/Tape & Reel, 13-inch		
UF2005-T	DO-15	4K/Tape & Reel, 13-inch		
UF2006-T	DO-15	4K/Tape & Reel, 13-inch		
UF2007-T	DO-15	4K/Tape & Reel, 13-inch		

6. For packaging details, visit our website at http://www.diodes.com/datasheets/ap02007.pdf.

IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Incorporated:

UF2002-T UF2003-T UF2005-T UF2006-T